NSN 5961-00-883-7047

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Inclosure Material:

Metal

Overall Length:

0.375 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

-35.0 collector to base voltage, dc and -35.0 collector to emitter voltage, dc and -30.0 emitter to base voltage, dc

Power Rating Per Characteristic:

750.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unc

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/197 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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